Diode Semiconductor Device - Page 1 of 1



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|-----------------------------------------------------------------------------------------------------|
| Inclosure Material: |
| Glass |
| Overall Length: |
| Between 0.360 inches and 0.375 inches |
| Terminal Length: |
| 1.100 inches |
| Overall Diameter: |
| Between 0.190 inches and 0.205 inches |
| Function For Which Designed: |
| Transient suppressor |
| Mounting Method: |
| Terminal |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 94.0 reverse voltage, instantaneous and 105.0 breakdown voltage, dc and 116.0 breakdown voltage, dc |
| Current Rating Per Characteristic: |
| 1.00 milliamperes drain current pascal |
| Maximum Operating Tempurature Per Measurement Point: |
| 175.0 degrees celsius ambient air |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Filg: |
| A110a0 |
| |